NSN 5961-00-275-7576

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View Online at https://aerobasegroup.com/nsn/5961-00-275-7576 **Inclosure Material:** Ceramic **Overall Length:** 0.785 inches **Terminal Length:** 0.120 inches **Overall Height:** 0.280 inches **Overall Width:** 0.300 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-116 **Electrode Internally-electrically Connected To Case:** Collector **Component Name And Quantity:** 4 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 60.0 collector to base voltage/static/emitter open all transistor and 40.0 collector to emitter voltage/static/base open all transistor and 5.0 breakdown voltage, emitter-to-base, collector open all transistor **Current Rating Per Characteristic:** 0.50 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 1900.0 milliwatts small-signal input power, common-collector preset all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Design analysis; transistor junction pattern arrangement: npn **Nuclear Hardness Critical Feature:** Hardened **Terminal Type And Quantity:** 14 pin Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

No

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